FRAUNHOFER INSTITUTE FOR MICROELECTRONIC CIRCUITS AND SYSTEMS IMS

Director: Prof. Dr. rer. nat. Anton Grabmaier

Fraunhofer-Gesellschaft

Facts







Joseph von Fraunhofer (1787 - 1826)

- Non-profit organization
- Founded in 1949
- 67 institutes
- Total personnel: approx. 24,000 employees
- Budget: More than 2 billion EUR total annual research budget
- Roughly 1.7 billion EUR is generated through contract research



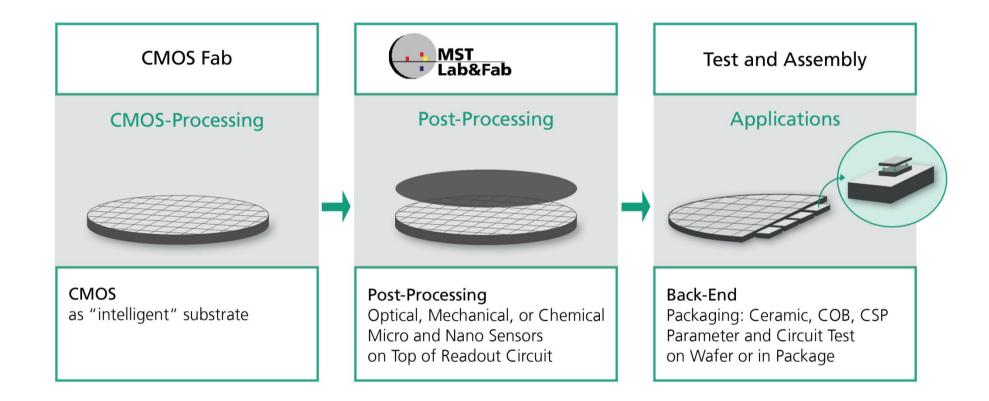
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Fraunhofer IMS Competences

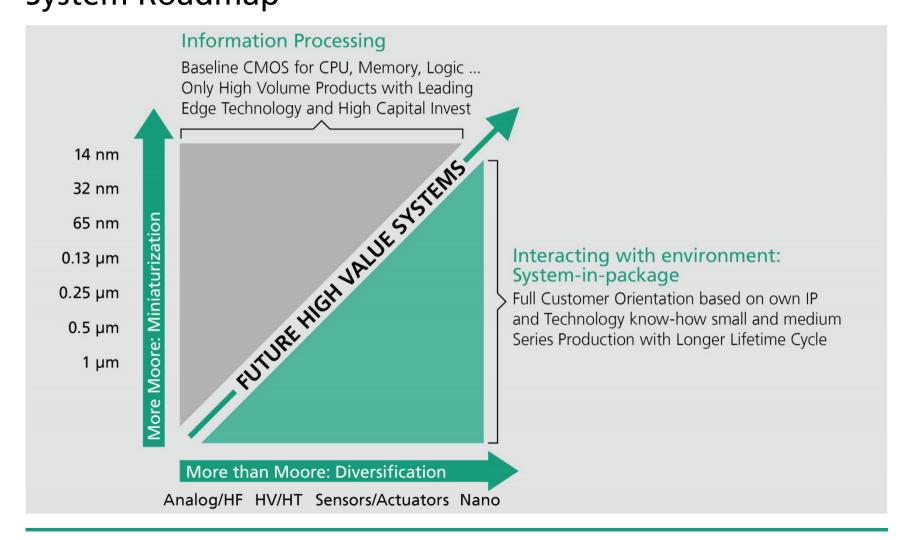
Fraunhofer IMS has been transferring its know-how into customer-specific products for more than 30 years.

- We develop CMOS based systems, operate process development and circuit design as well as ASIC manufacturing.
- As a trendsetter in intelligent microsystems technology (MST) we combine sensors with microelectronic interfaces.
- Our system development integrates sensors with wireless systems into innovative customer products.

Fraunhofer IMS Infrastructure



Fraunhofer IMS System Roadmap



Fraunhofer IMS

Quality Management System





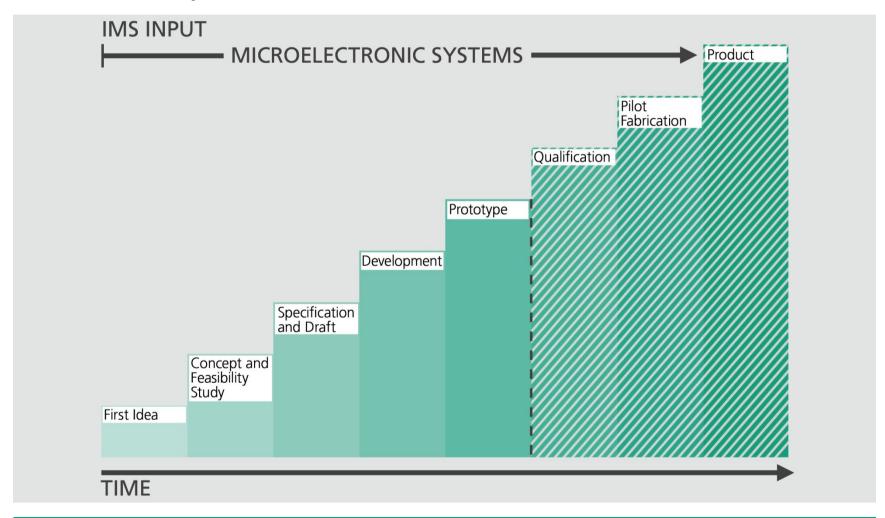
DIN EN ISO 9001 Certification

ISO/TS 16949 Certification



Fraunhofer IMS

From Concept to Product



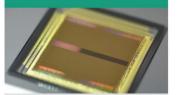
Fraunhofer IMS Business Fields





Pressure Sensors Medical Implants

CMOS Image Sensors



Time-of-Flight Imaging
Ultrasensitive Images

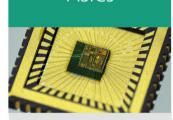
Wireless and Transponder Systems



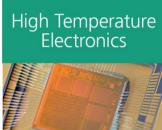
Sensor Transponders and Readers

Wireless Data and Energy Transmission

ASICs



Chip-Design Fabrication



Design for high Temperature SOI CMOS Technology

Electronic Assistance Systems

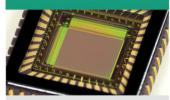


Embedded Systems

Distributed Systems and

Networks

Devices and Technologies



CMOS Processes
Smart Sensors

IR Imagers



Read-out Circuits
Infrared Sensors

Biohybrid Systems



Glucose and Lactate Sensors Bio Sensors

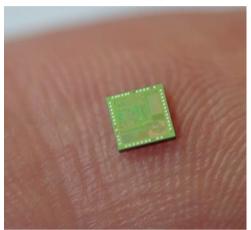
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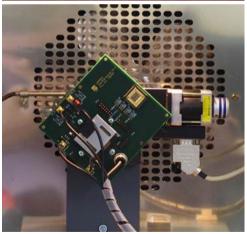


Common Research and Development

Reference Projects: ASICs (IC)

Capacitive Readout IC

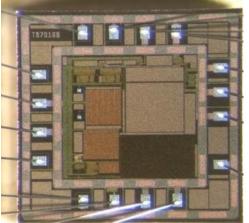




- Key Specifications
 - Input referred noise down to 60 zF/Sqrt(Hz)
 - Bandwidth: 0 Hz 10 kHz
 - Dynamic range: 120 dB
 - Measurement range: ±0.75 pF ±3.0 pF
- Unique Selling Points
 - Integrated temperature sensor for MEMS TCO compensation
 - 4 tunable gain settings
 - Internal trimming capacitances: each up to 1 pF
 - Optional 11 bit ADC and digital interface

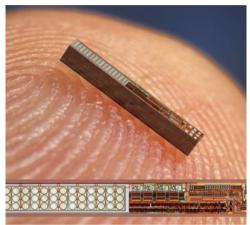
Reference Projects: High Temperature Electronics High Temperature Proximity Switch





- Key Specifications
 - Operating temperature up to 250 °C
 - Configurable output (NPN, PNP, NO, NC)
 - Adjustable switching distance (up to x2)
 - On-Chip calibration
- Unique Selling Points
 - Sensor electronic for harsh environment
 - High temperature operation
 - SOI CMOS integrated solution
 - No detached electronics

Reference Projects: Pressure Sensor Systems (PSS) Shunt Sensor





- Key Specifications
 - Wireless measurement of intracranial pressure
 - The transponder is encapsulated in metal
 - HF-frequency: 133 kHz
 - Operation distance 0 5 cm
- Unique Selling Points
 - Low power consumption and miniaturization
 - Transponder capability
 - Manufacturing of ASIC and reader unit
 - ASIC and reader for approved medical implants

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